



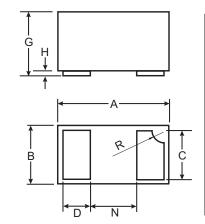
SURFACE MOUNT ZENER DIODE

Features

- Planar Die Construction
- Ultra-Small Leadless Surface Mount Package
- Ideally Suited for Automated Assembly Processes
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: Cathode Dot
- Terminals: Finish NiPdAu annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: 9COrdering Information: See Last Page
- Weight: 0.001 grams



DFN1006-2			
Dim	Min	Max	Тур
Α	0.95	1.05	1.00
В	0.55	0.65	0.60
С	0.45	0.55	0.50
D	0.20	0.30	0.25
G	0.47	0.53	0.50
Н	0	0.05	0.03
N	_	_	0.40
R	0.05	0.15	0.10
All Dimensions in mm			

Maximum Ratings @ $T_A = 25^{\circ}C$ unless otherwise specified

	Characteristic	Symbol	Value	Unit
Forward Voltage (Note 3)	@ I _F = 10mA	V _F	0.9	V
Operating and Storage Temperature Range		T _{j,} T _{STG}	-65 to +150	°C
Peak Pulse Power (tp = 8 x 20 μs) (Note 4)		P _{pk}	85	W
Peak Pulse Current (tp =	8 x 20 μs) (Note 4)	I _{pp}	4.5	Α
ESD Rating	Human Body Model	V_{pp}	8	kV
	Machine Model		400	V
	IEC61000-4-2 Air Discharge		25	kV
	IEC61000-4-2 Contact Discharge		8	kV

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Short duration pulse test used to minimize self-heating effect.
- Part mounted on FR-4 PC board with recommended pad layout, as per http://www.diodes.com/datasheets/ap02001.pdf.

Thermal Characteristics @ TA = 25°C unless otherwise specified

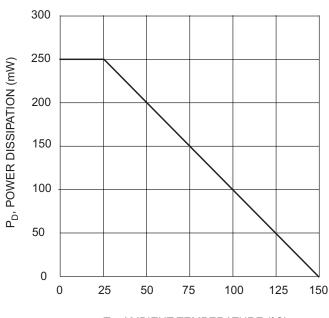
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _d	250	mW
Thermal Resistance, Junction to Ambient Air (Note 4)	$R_{ heta JA}$	500	°C/W



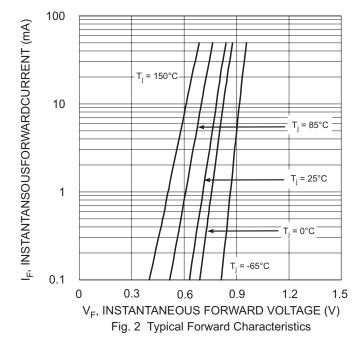
Electrical Characteristics @ T_A = 25°C unless otherwise specified

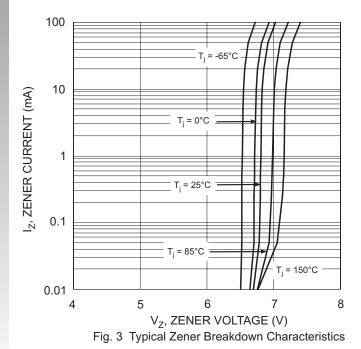
Characteristic		Symbol	Value	Unit
Reverse Standoff Voltage		V _{RWM}	5	V
Breakdown Voltage @ I _T = 5mA (Note 5)	Minimum	V_{BR}	6.4	V
	Maximum		7.2	
Maximum Reverse Leakage @ V _{RWM}		I _R	0.5	μΑ
Maximum Clamping Voltage @ I _{pp} = 4.5A (tp = 8x20μs)		V _C	19	V
Typical Total Capacitance (V _R = 0V, f = 1MHz)		C _T	65	pF

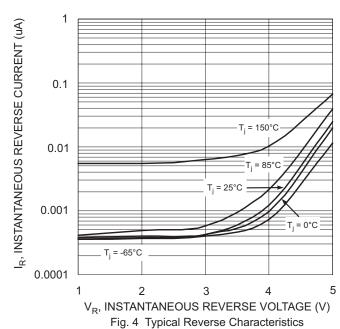
Notes: 5. Short duration test pulse used to minimize self-heating effect.



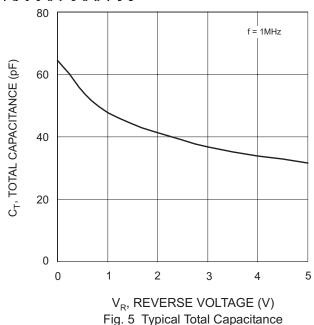
T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Power Derating Curve











Ordering Information (Note 6)

Device	Packaging	Shipping
TPD6V8LP-7	DFN1006-2	3000/Tape & Reel

Notes:

6. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

• 9C

9C = Product Type Marking Code, Dot Denotes Cathode Side

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